(Transistor)

2SC5383

For Low Frequency Amplify Application Silicon NPN Epitaxial Type Ultra Super Mini

DESCRIPTION

2SC5383 is a super mini silicon NPN epitaxial type transistor designed for low frequency voltage amplify application.

FEATURE

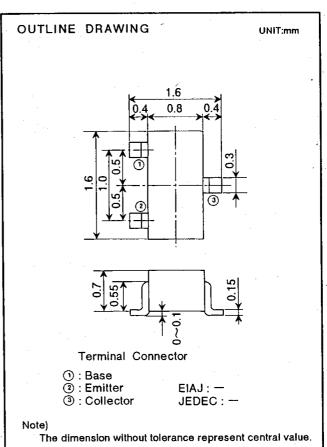
- Low collector to emitter saturation voltage.
 VCE(sat)=0.3V max (@ 1 c=100mA,I B=10mA)
- · Excellent linearity DC forward current gain
- · Super mini package for easy mounting

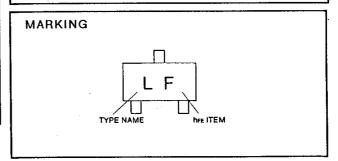
APPLICATION

For hybrid IC, small type machine low frequency voltage amplify application.

MAXIMUM RATINGS (Ta=25°C)

SYMBOL	PARAMETER	RATINGS	UNIT
Vсво	Collector to Base voltage	50	٧
VEBO	Emitter to Base voltage	6	٧
VCEO	Collector to Emitter voltage	50	٧
lc.	Collector current	200	mA
Pc	Collector dissipation (Ta=25℃)	125	mW
Tj	Junction temperature	+125	°C
Tstg	Storage temperature	-55 to +125	°C





ELECTRICAL CHARACTERISTICS (Ta=25°C)

SYMBOL	PARAMETER	TESTCONDITIONS	LIMITS			
			MIN	TYP	MAX	UNIT
V(BR)CEO	C to E break down voltage	I C=100 μ A, RBE=∞	50			V
Ісво	Collector cut off current	VcB=50V, I E=0			0.1	μΑ
I ЕВО	Emitter cut off current	VEB=6V, I C=0			0.1	μΑ
hFE *	DC forward current gain	VcE=6V, I c=1mA	150		800	
hFE	DC forward current gain	Vce=6V, I c=0.1mA	90			
VCE(sat)	C to E saturation voltage	I c=100mA, I B=10mA			0.3	V
fr .	Gain band width product	VcE=6V, I E=-10mA		200		MHz
Соь	Collector output capacitance	VcB=6V, I E=0, f=1MHz		2.5		pF
NF	Noise figure	VcE=6V, I E=-0.1mA, f=1kHz, Rg=2kΩ			15	dB

ITEM	E	F	G
hfE	150~300	250~500	400~800

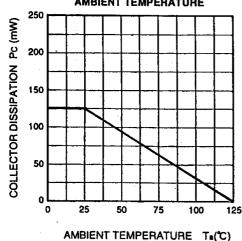
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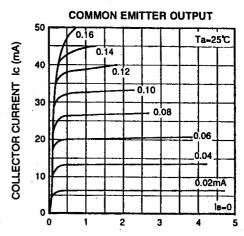
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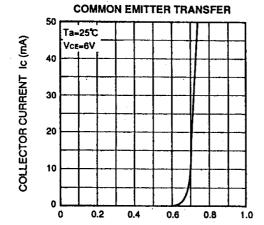
TYPICAL CHARACTERISTICS

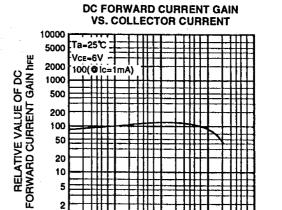






COLLECTOR TO EMITTER VOLTAGE VCE(V)

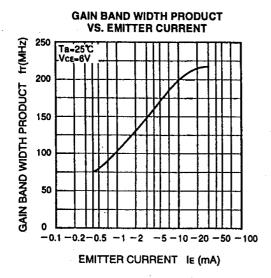


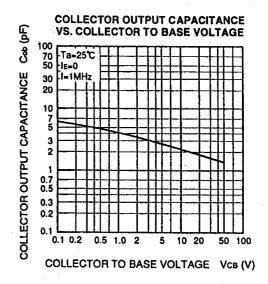


5 10 20 50 100 200

BASE TO EMITTER VOLTAGE VBE(V) COLLECTOR CURRENT IC (mA)

0.1 0.2 0.5 1.0 2

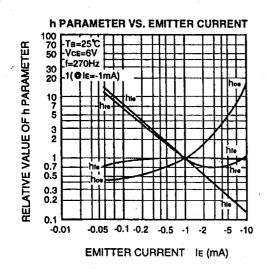


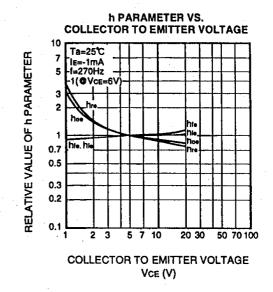


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COMMON EMITTER h PARAMETER (TYPICAL VALUE)

Symbol	Parameter	Test conditions	Limits	Unit
hie	Closed loop small signal input impedance	Ta=25℃	8.5	kΩ
hre	Open loop small signal reverse voltage amplification factor	VCE=6V	0.1	×10-3
hle	Closed loop small signal forward current amplification factor	IE=-1mA f=270Hz	300	
hoe	Open loop small signal output admittance		5.5	μS



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